

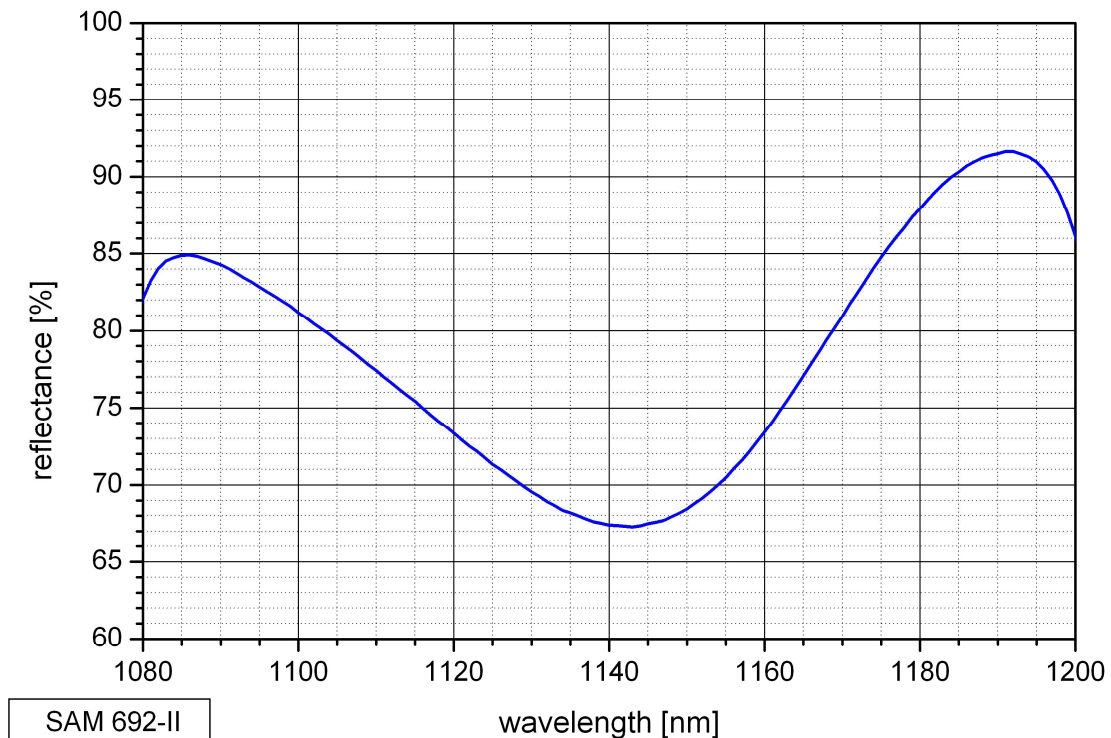
SAM™ Data Sheet SAM-1150-32-1ps-x, $\lambda = 1150$ nm

Laser wavelength	$\lambda = 1150$ nm
High reflection band	$\lambda = 1080 \dots 1200$ nm
Absorbance	$A_0 = 32$ %
Modulation depth	$\Delta R = 20$ %
Non-saturable loss	$A_{ns} = 12$ %
Saturation fluence	$\Phi_{sat} = 70$ $\mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 1$ ps
Damage threshold	$\Phi = 700$ $\mu\text{J}/\text{cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

- x** = 0 unmounted
- x** = 12.7 g glued on a copper heat sink with 12.7 mm \varnothing
- x** = 25.4 g glued on a copper heat sink with with 25.4 mm \varnothing
- x** = 12.7 s soldered on a copper heat sink with with 12.7 mm \varnothing
- x** = 25.4 s soldered on a copper heat sink with with 25.4 mm \varnothing
- x** = 25.0 w soldered on copper heat sink with with 25.0 mm \varnothing
- x** = FC mounted on a 1 m single mode fiber cable with FC connector

Low intensity spectral reflectance



SAM 692-II